



EMK31 H 2 H -34.905M

RoHS Compliant (Pb-free) 4 Pad 2.5mm x 3.2mm SMD 1.8Vdc LVCMOS MEMS Oscillator

Frequency Tolerance/Stability ±50ppm Maximum over -40°C to +85°C Duty Cycle Nominal Frequency 34.905MHz

- Output Control Function

Tri-State (Disabled Output: High Impedance)

| ELECTRICAL SPECIFICATIONS | | |
|-------------------------------|------------|--|
| Nominal Frequency | 34.905MHz | |
| Frequency Tolerance/Stability | ±50ppm Max | |

#50ppm Maximum over -40°C to +85°C (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, 260°C Reflow, Shock, and Vibration)

Aging at 25°C ±1ppm Maximum First Year

Operating Temperature Range -40°C to +85°C

 Supply Voltage
 1.8Vdc ±5%

 Input Current
 18mA Maximum

Output Voltage Logic High (Voh)
90% of Vdd Minimum (IOH=-8mA)
Output Voltage Logic Low (Vol)
10% of Vdd Maximum (IOL=+8mA)

Rise/Fall Time 2nSec Maximum (Measured from 20% to 80% of waveform)

Duty Cycle 50 ±5(%) (Measured at 50% of waveform)

Load Drive Capability 15pF Maximum

Output Logic Type CMOS

Output Control Function Tri-State (Disabled Output: High Impedance)

Output Control Input Voltage +0.7Vdd Minimum or No Connect to Enable Output, +0.3Vdd Maximum to Disable Output

Peak to Peak Jitter (tPK)250pSec Maximum, 100pSec TypicalStart Up Time50mSec Maximum

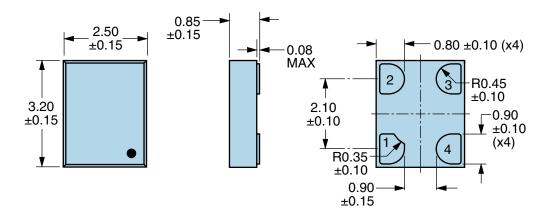
Storage Temperature Range -55°C to +125°C

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS

| ESD Susceptibility | MIL-STD-883, Method 3015, Class 2, HBM 2000V |
|------------------------------|---|
| Flammability | UL94-V0 |
| Mechanical Shock | MIL-STD-883, Method 2002, Condition G, 30,000G |
| Moisture Resistance | MIL-STD-883, Method 1004 |
| Moisture Sensitivity Level | J-STD-020, MSL 1 |
| Resistance to Soldering Heat | MIL-STD-202, Method 210, Condition K |
| Resistance to Solvents | MIL-STD-202, Method 215 |
| Solderability | MIL-STD-883, Method 2003 (Pads on Bottom of Package Only) |
| Temperature Cycling | MIL-STD-883, Method 1010, Condition B |
| Thermal Shock | MIL-STD-883, Method 1011, Condition B |
| Vibration | MIL-STD-883, Method 2007, Condition A, 20G |



MECHANICAL DIMENSIONS (all dimensions in millimeters)

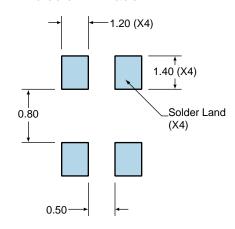


| PIN | CONNECTION |
|-----|----------------|
| 1 | Tri-State |
| 2 | Ground |
| 3 | Output |
| 4 | Supply Voltage |

| LINE | MARKING |
|------|---|
| 1 | XXXX or XXXXX XXXX or XXXXX=Ecliptek Manufacturing Lot Code |

Suggested Solder Pad Layout

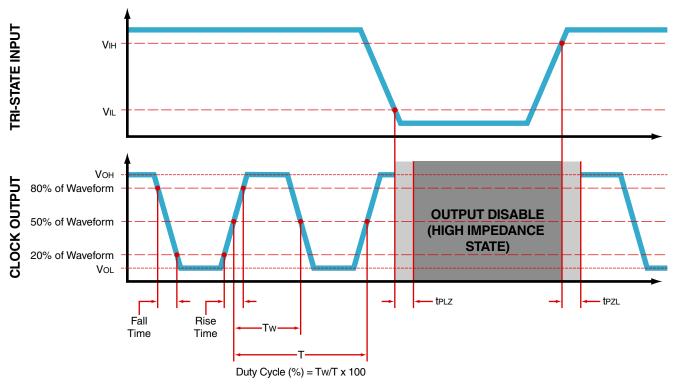
All Dimensions in Millimeters



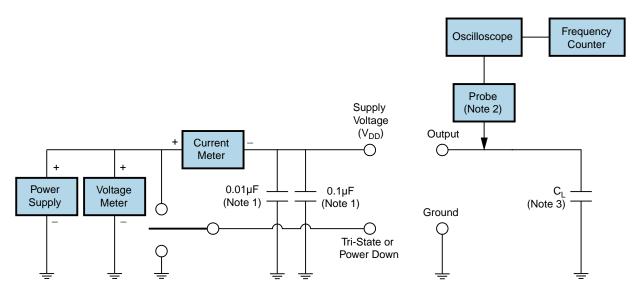
All Tolerances are ±0.1



OUTPUT WAVEFORM & TIMING DIAGRAM



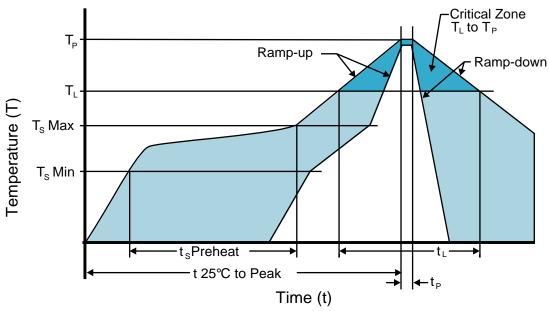
Test Circuit for CMOS Output



- Note 1: An external 0.1µF low frequency tantalum bypass capacitor in parallel with a 0.01µF high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.
- Note 3: Capacitance value \dot{C}_L includes sum of all probe and fixture capacitance.



Recommended Solder Reflow Methods



High Temperature Infrared/Convection

| T _s MAX to T _∟ (Ramp-up Rate) | 3°C/second Maximum |
|---|--------------------------------------|
| Preheat | |
| - Temperature Minimum (Ts MIN) | 150°C |
| - Temperature Typical (T _s TYP) | 175°C |
| - Temperature Maximum (T _s MAX) | 200°C |
| - Time (t _s MIN) | 60 - 180 Seconds |
| Ramp-up Rate (T _L to T _P) | 3°C/second Maximum |
| Time Maintained Above: | |
| - Temperature (T∟) | 217°C |
| - Time (t∟) | 60 - 150 Seconds |
| Peak Temperature (T _P) | 260°C Maximum for 10 Seconds Maximum |
| Target Peak Temperature (T _P Target) | 250°C +0/-5°C |
| Time within 5°C of actual peak (tp) | 20 - 40 seconds |
| Ramp-down Rate | 6°C/second Maximum |
| Time 25°C to Peak Temperature (t) | 8 minutes Maximum |
| Moisture Sensitivity Level | Level 1 |
| | |



Recommended Solder Reflow Methods



Low Temperature Infrared/Convection 240°C

| T _S MAX to T _L (Ramp-up Rate) | 5°C/second Maximum |
|---|--|
| Preheat | |
| - Temperature Minimum (T _s MIN) | N/A |
| - Temperature Typical (T _S TYP) | 150°C |
| - Temperature Maximum (T _s MAX) | N/A |
| - Time (t _s MIN) | 60 - 120 Seconds |
| Ramp-up Rate (T _L to T _P) | 5°C/second Maximum |
| Time Maintained Above: | |
| - Temperature (T∟) | 150°C |
| - Time (t∟) | 200 Seconds Maximum |
| Peak Temperature (T _P) | 240°C Maximum |
| Target Peak Temperature (T _P Target) | 240°C Maximum 1 Time / 230°C Maximum 2 Times |
| Time within 5°C of actual peak (tp) | 10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time |
| Ramp-down Rate | 5°C/second Maximum |
| Time 25°C to Peak Temperature (t) | N/A |
| Moisture Sensitivity Level | Level 1 |

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.